

	L #	Hits	Search Text	DBs
1	L1	537609	"257"/\$.ccls. "438"/\$.ccls. "216"/\$.ccls. "156"/\$.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
2	L2	105	1 and (oxide near etch\$3) near (apparatus or chamber)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
3	L3	2	2 and (different near frequenc\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
4	L4	2	3 and ((top and bottom) or (upper and lower)) near electrode	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
5	L5	72	(igarashi-yoshiki or balasubramaniam-vaidya- nathan or suemasa-tomoki or inazawa-koichiro).in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
6	L6	3	5 and (different near frequenc\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
7	L7	4320	((plasma or etch\$3) near apparatus).ti.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
8	L8	270	7 and.((top and bottom) or (upper and lower)) near electrode	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
9	L9	5	8 and (different near frequenc\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
10	L10	18435	((plasma or etch\$3) near apparatus)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
11	L11	755	10 and (oxide near etch\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
12	L12	0	11 and hexafluorobutadiene	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
13	L13	151	11 and ((top and bottom) or (upper and lower)) near electrode	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
14	L14	9	13 and (different near. frequenc\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB